

N-Cyclohexyl-N-(prop-2-en-1-yl)-benzenesulfonamide

Islam Ullah Khan,^a Zeeshan Haider,^a Muhammad Zia-ur-Rehman,^{b*} Muhammad Nadeem Arshad^a and Muhammad Shafiq^a

^aDepartment of Chemistry, Government College University, Lahore 54000, Pakistan, and ^bApplied Chemistry Research Centre, PCSIR Laboratories Complex, Ferozpur Road, Lahore 54600, Pakistan

Correspondence e-mail: rehman_pcsir@hotmail.com

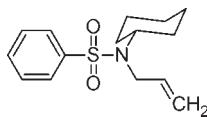
Received 10 November 2009; accepted 12 November 2009

Key indicators: single-crystal X-ray study; $T = 296\text{ K}$; mean $\sigma(\text{C}-\text{C}) = 0.004\text{ \AA}$; R factor = 0.052; wR factor = 0.144; data-to-parameter ratio = 21.8.

The title compound, $C_{15}H_{21}NO_2S$, synthesized by *N*-alkylation of cyclohexylamine benzenesulfonamide with allyl iodide, is of interest as a precursor to biologically active sulfur-containing heterocyclic compounds. The cyclohexane ring is in a chair form and its mean plane makes a dihedral angle of $53.84(12)^\circ$ with the phenyl ring.

Related literature

For the synthesis of related molecules, see: Arshad *et al.* (2009); Zia-ur-Rehman *et al.* (2009). For biological applications of sulfonamides, see: Connor (1998); Berredjem *et al.* (2000); Lee & Lee (2002); Xiao & Timberlake (2000). For a related structure, see: Khan *et al.* (2009). For bond-length data, see: Allen *et al.* (1987).



Experimental

Crystal data

$C_{15}H_{21}NO_2S$
 $M_r = 279.39$

Monoclinic, $P2_1/n$

$a = 8.4911(5)\text{ \AA}$
 $b = 11.4176(6)\text{ \AA}$
 $c = 15.6274(10)\text{ \AA}$

$\beta = 94.188(3)^\circ$
 $V = 1511.00(15)\text{ \AA}^3$
 $Z = 4$
Mo $K\alpha$ radiation

$\mu = 0.21\text{ mm}^{-1}$
 $T = 296\text{ K}$
 $0.38 \times 0.18 \times 0.12\text{ mm}$

Data collection

Bruker APEXII CCD area-detector diffractometer
Absorption correction: multi-scan (*SADABS*; Sheldrick, 1996)
 $T_{\min} = 0.924$, $T_{\max} = 0.975$

16559 measured reflections
3746 independent reflections
2179 reflections with $I > 2\sigma(I)$
 $R_{\text{int}} = 0.047$

Refinement

$R[F^2 > 2\sigma(F^2)] = 0.052$
 $wR(F^2) = 0.144$
 $S = 1.02$
3746 reflections

172 parameters
H-atom parameters constrained
 $\Delta\rho_{\max} = 0.43\text{ e \AA}^{-3}$
 $\Delta\rho_{\min} = -0.34\text{ e \AA}^{-3}$

Data collection: *APEX2* (Bruker, 2007); cell refinement: *SAINT* (Bruker, 2007); data reduction: *SAINT*; program(s) used to solve structure: *SHELXS97* (Sheldrick, 2008); program(s) used to refine structure: *SHELXL97* (Sheldrick, 2008); molecular graphics: *PLATON* (Spek, 2009) and *Mercury* (Macrae *et al.*, 2006); software used to prepare material for publication: *WinGX* (Farrugia, 1999) and *PLATON*.

The authors are grateful to the Higher Education Commission of Pakistan for financial support to purchase the diffractometer.

Supplementary data and figures for this paper are available from the IUCr electronic archives (Reference: IS2487).

References

- Allen, F. H., Kennard, O., Watson, D. G., Brammer, L., Orpen, A. G. & Taylor, R. (1987). *J. Chem. Soc. Perkin Trans 2*, pp. S1–19.
Arshad, M. N., Zia-ur-Rehman, M. & Khan, I. U. (2009). *Acta Cryst. E65*, o2596.
Berredjem, M., Régainia, Z., Djahoudi, A., Aouf, N. E., Dewinter, G. & Montero, J. L. (2000). *Phosphorus Sulfur Silicon Relat. Elem.* **165**, 249–264.
Bruker (2007). *APEX2* and *SAINT*. Bruker AXS Inc., Madison, Wisconsin, USA.
Connor, E. E. (1998). *Prim. Care Update Ob. Gyn.* **5**, 32–35.
Farrugia, L. J. (1999). *J. Appl. Cryst.* **32**, 837–838.
Khan, I. U., Haider, Z., Zia-ur-Rehman, M., Arshad, M. N. & Shafiq, M. (2009). *Acta Cryst. E65*, o2867.
Lee, J. S. & Lee, C. H. (2002). *Bull. Korean Chem. Soc.* **23**, 167–169.
Macrae, C. F., Edgington, P. R., McCabe, P., Pidcock, E., Shields, G. P., Taylor, R., Towler, M. & van de Streek, J. (2006). *J. Appl. Cryst.* **39**, 453–457.
Sheldrick, G. M. (1996). *SADABS*. University of Göttingen, Germany.
Sheldrick, G. M. (2008). *Acta Cryst. A64*, 112–122.
Spek, A. L. (2009). *Acta Cryst. D65*, 148–155.
Xiao, Z. & Timberlake, J. W. (2000). *J. Heterocycl. Chem.* **37**, 773–777.
Zia-ur-Rehman, M., Choudary, J. A., Elsegood, M. R. J., Siddiqui, H. L. & Khan, K. M. (2009). *Eur. J. Med. Chem.* **44**, 1311–1316.

supplementary materials

Acta Cryst. (2009). E65, o3102 [doi:10.1107/S1600536809048077]

N-Cyclohexyl-N-(prop-2-en-1-yl)benzenesulfonamide

I. U. Khan, Z. Haider, M. Zia-ur-Rehman, M. N. Arshad and M. Shafiq

Comment

Sulfonamides are familiar in the literature for their anti-malarial, anti-convulsant and anti-hypertensive (Connor, 1998; Xiao & Timberlake, 2000; Berredjem *et al.*, 2000; Lee & Lee, 2002) activities. As a part of our ongoing research program regarding the synthesis of sulfur containing heterocyclic compounds (Arshad *et al.*, 2009; Zia-ur-Rehman *et al.*, 2009; Khan *et al.*, 2009), we herein report the crystal structure of the title compound (Fig. 1).

In the title molecule, bond lengths and bond angles are within the normal ranges (Allen *et al.*, 1987). In the crystal structure, the phenyl ring is essentially planar while the cyclohexane ring is in a chair form. No significant hydrogen bond interactions are observed in the title molecule. The dihedral angle between the phenyl and cyclohexane rings is 53.84 (12)°.

Experimental

A mixture of *N*-cyclohexylbenzene sulfonamide (1.0 g, 0.43 mmol), sodium hydride (0.21 g, 0.88 mmol) and *N,N*-dimethyl-formamide (10.0 ml) was stirred at room temperature for half an hour followed by addition of allyl iodide (0.144 g, 0.86 mmol). Stirring was continued further for a period of three hours and the contents were poured over crushed ice. Precipitated product was isolated, washed and crystallized from methanol.

Refinement

All hydrogen atoms were identified in the difference map. However, they were fixed in ideal positions and treated as riding on their parent atoms. The following distances were used: C_{methyl}—H = 0.98 Å and C_{aromatic}—H = 0.95 Å. *U*_{iso}(H) was set to 1.2*U*_{eq}(C) or 1.5*U*_{eq}(C_{methyl}).

Figures

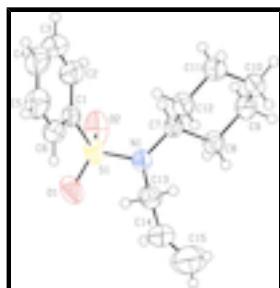


Fig. 1. The molecular structure of the title compound, with displacement ellipsoids at the 50% probability level.

supplementary materials

N-Cyclohexyl-*N*-(prop-2-en-1-yl)benzenesulfonamide

Crystal data

C ₁₅ H ₂₁ NO ₂ S	$F_{000} = 600$
$M_r = 279.39$	$D_x = 1.228 \text{ Mg m}^{-3}$
Monoclinic, $P2_1/n$	Mo $K\alpha$ radiation, $\lambda = 0.71073 \text{ \AA}$
Hall symbol: -P 2yn	Cell parameters from 3312 reflections
$a = 8.4911 (5) \text{ \AA}$	$\theta = 2.2\text{--}21.3^\circ$
$b = 11.4176 (6) \text{ \AA}$	$\mu = 0.21 \text{ mm}^{-1}$
$c = 15.6274 (10) \text{ \AA}$	$T = 296 \text{ K}$
$\beta = 94.188 (3)^\circ$	Needles, light yellow
$V = 1511.00 (15) \text{ \AA}^3$	$0.38 \times 0.18 \times 0.12 \text{ mm}$
$Z = 4$	

Data collection

Bruker APEXII CCD area-detector diffractometer	3746 independent reflections
Radiation source: fine-focus sealed tube	2179 reflections with $I > 2\sigma(I)$
Monochromator: graphite	$R_{\text{int}} = 0.047$
$T = 296 \text{ K}$	$\theta_{\text{max}} = 28.3^\circ$
φ and ω scans	$\theta_{\text{min}} = 2.2^\circ$
Absorption correction: multi-scan (<i>SADABS</i> ; Sheldrick, 1996)	$h = -11 \rightarrow 11$
$T_{\text{min}} = 0.924$, $T_{\text{max}} = 0.975$	$k = -15 \rightarrow 15$
16559 measured reflections	$l = -19 \rightarrow 20$

Refinement

Refinement on F^2	Secondary atom site location: difference Fourier map
Least-squares matrix: full	Hydrogen site location: inferred from neighbouring sites
$R[F^2 > 2\sigma(F^2)] = 0.052$	H-atom parameters constrained
$wR(F^2) = 0.144$	$w = 1/[\sigma^2(F_o^2) + (0.0594P)^2 + 0.3938P]$
$S = 1.02$	where $P = (F_o^2 + 2F_c^2)/3$
3746 reflections	$(\Delta/\sigma)_{\text{max}} < 0.001$
172 parameters	$\Delta\rho_{\text{max}} = 0.43 \text{ e \AA}^{-3}$
Primary atom site location: structure-invariant direct methods	$\Delta\rho_{\text{min}} = -0.34 \text{ e \AA}^{-3}$
	Extinction correction: none

Special details

Geometry. All e.s.d.'s (except the e.s.d. in the dihedral angle between two l.s. planes) are estimated using the full covariance matrix. The cell e.s.d.'s are taken into account individually in the estimation of e.s.d.'s in distances, angles and torsion angles; correlations

between e.s.d.'s in cell parameters are only used when they are defined by crystal symmetry. An approximate (isotropic) treatment of cell e.s.d.'s is used for estimating e.s.d.'s involving l.s. planes.

Refinement. Refinement of F^2 against ALL reflections. The weighted R -factor wR and goodness of fit S are based on F^2 , conventional R -factors R are based on F , with F set to zero for negative F^2 . The threshold expression of $F^2 > \sigma(F^2)$ is used only for calculating R -factors(gt) etc. and is not relevant to the choice of reflections for refinement. R -factors based on F^2 are statistically about twice as large as those based on F , and R -factors based on ALL data will be even larger.

Fractional atomic coordinates and isotropic or equivalent isotropic displacement parameters (\AA^2)

	x	y	z	$U_{\text{iso}}^*/U_{\text{eq}}$
S1	0.27668 (7)	0.31209 (5)	0.25071 (4)	0.0519 (2)
O1	0.3713 (2)	0.21435 (17)	0.27943 (11)	0.0744 (6)
O2	0.3425 (2)	0.42730 (16)	0.25495 (14)	0.0776 (6)
N1	0.1228 (2)	0.31154 (15)	0.30554 (12)	0.0460 (5)
C1	0.2123 (2)	0.28696 (18)	0.14300 (14)	0.0438 (5)
C2	0.1843 (3)	0.3808 (2)	0.08789 (19)	0.0714 (8)
H2	0.2024	0.4570	0.1073	0.086*
C3	0.1297 (4)	0.3605 (3)	0.0047 (2)	0.0942 (11)
H3	0.1097	0.4233	-0.0324	0.113*
C4	0.1044 (4)	0.2497 (4)	-0.02421 (19)	0.0881 (10)
H4	0.0692	0.2370	-0.0812	0.106*
C5	0.1303 (3)	0.1558 (3)	0.03010 (18)	0.0744 (8)
H5	0.1110	0.0801	0.0101	0.089*
C6	0.1849 (3)	0.1740 (2)	0.11428 (16)	0.0534 (6)
H6	0.2032	0.1108	0.1513	0.064*
C7	0.0098 (2)	0.41024 (18)	0.29605 (14)	0.0416 (5)
H7	0.0635	0.4740	0.2679	0.050*
C8	-0.0307 (3)	0.45575 (19)	0.38291 (14)	0.0485 (6)
H8A	0.0654	0.4776	0.4164	0.058*
H8B	-0.0819	0.3943	0.4136	0.058*
C9	-0.1402 (3)	0.5618 (2)	0.37271 (16)	0.0584 (7)
H9A	-0.1702	0.5861	0.4287	0.070*
H9B	-0.0841	0.6263	0.3482	0.070*
C10	-0.2872 (3)	0.5350 (2)	0.31574 (16)	0.0573 (6)
H10A	-0.3497	0.4769	0.3433	0.069*
H10B	-0.3503	0.6055	0.3078	0.069*
C11	-0.2460 (3)	0.4895 (2)	0.22941 (16)	0.0621 (7)
H11A	-0.1928	0.5504	0.1993	0.074*
H11B	-0.3421	0.4689	0.1953	0.074*
C12	-0.1393 (3)	0.3822 (2)	0.23980 (15)	0.0539 (6)
H12A	-0.1959	0.3190	0.2655	0.065*
H12B	-0.1109	0.3563	0.1838	0.065*
C13	0.0737 (3)	0.20179 (19)	0.34549 (16)	0.0566 (6)
H13A	0.1046	0.1358	0.3114	0.068*
H13B	-0.0404	0.2007	0.3464	0.068*
C14	0.1475 (4)	0.1896 (2)	0.4359 (2)	0.0795 (9)
H14	0.2546	0.2069	0.4439	0.095*
C15	0.0842 (6)	0.1601 (3)	0.4985 (3)	0.1242 (14)

supplementary materials

H15A	-0.0228	0.1417	0.4943	0.149*
H15B	0.1420	0.1557	0.5513	0.149*

Atomic displacement parameters (\AA^2)

	U^{11}	U^{22}	U^{33}	U^{12}	U^{13}	U^{23}
S1	0.0389 (3)	0.0632 (4)	0.0529 (4)	0.0041 (3)	-0.0012 (3)	-0.0167 (3)
O1	0.0604 (11)	0.1025 (14)	0.0580 (12)	0.0354 (10)	-0.0124 (9)	-0.0179 (10)
O2	0.0527 (10)	0.0808 (13)	0.1011 (15)	-0.0240 (9)	0.0184 (10)	-0.0401 (11)
N1	0.0466 (11)	0.0490 (10)	0.0423 (11)	0.0079 (8)	0.0035 (9)	-0.0034 (8)
C1	0.0376 (11)	0.0515 (12)	0.0429 (13)	0.0029 (9)	0.0074 (10)	-0.0026 (10)
C2	0.090 (2)	0.0625 (16)	0.0642 (19)	0.0097 (14)	0.0200 (16)	0.0112 (14)
C3	0.114 (3)	0.112 (3)	0.058 (2)	0.044 (2)	0.0161 (19)	0.026 (2)
C4	0.072 (2)	0.149 (3)	0.0426 (17)	0.027 (2)	-0.0041 (14)	-0.005 (2)
C5	0.0732 (19)	0.093 (2)	0.0562 (18)	-0.0054 (16)	0.0002 (15)	-0.0247 (16)
C6	0.0576 (15)	0.0552 (14)	0.0473 (14)	0.0014 (11)	0.0037 (12)	-0.0037 (11)
C7	0.0413 (12)	0.0455 (11)	0.0380 (12)	0.0012 (9)	0.0026 (10)	-0.0027 (9)
C8	0.0505 (13)	0.0538 (13)	0.0409 (13)	0.0021 (10)	0.0010 (11)	-0.0096 (10)
C9	0.0706 (17)	0.0520 (13)	0.0534 (15)	0.0092 (12)	0.0098 (13)	-0.0102 (11)
C10	0.0553 (15)	0.0609 (14)	0.0561 (16)	0.0170 (12)	0.0065 (12)	0.0024 (12)
C11	0.0565 (15)	0.0786 (17)	0.0496 (16)	0.0154 (13)	-0.0053 (12)	-0.0003 (13)
C12	0.0515 (14)	0.0666 (15)	0.0424 (14)	0.0077 (11)	-0.0056 (11)	-0.0133 (11)
C13	0.0663 (16)	0.0484 (13)	0.0549 (16)	0.0073 (11)	0.0034 (13)	-0.0028 (11)
C14	0.097 (2)	0.0728 (18)	0.070 (2)	0.0197 (16)	0.0169 (18)	0.0238 (16)
C15	0.164 (4)	0.111 (3)	0.097 (3)	0.014 (3)	0.009 (3)	0.025 (2)

Geometric parameters (\AA , $^\circ$)

S1—O1	1.4283 (18)	C8—H8A	0.9700
S1—O2	1.4289 (17)	C8—H8B	0.9700
S1—N1	1.6136 (19)	C9—C10	1.511 (4)
S1—C1	1.755 (2)	C9—H9A	0.9700
N1—C13	1.474 (3)	C9—H9B	0.9700
N1—C7	1.481 (2)	C10—C11	1.510 (3)
C1—C6	1.380 (3)	C10—H10A	0.9700
C1—C2	1.385 (3)	C10—H10B	0.9700
C2—C3	1.368 (4)	C11—C12	1.525 (3)
C2—H2	0.9300	C11—H11A	0.9700
C3—C4	1.355 (5)	C11—H11B	0.9700
C3—H3	0.9300	C12—H12A	0.9700
C4—C5	1.375 (4)	C12—H12B	0.9700
C4—H4	0.9300	C13—C14	1.509 (4)
C5—C6	1.378 (4)	C13—H13A	0.9700
C5—H5	0.9300	C13—H13B	0.9700
C6—H6	0.9300	C14—C15	1.198 (4)
C7—C8	1.516 (3)	C14—H14	0.9300
C7—C12	1.522 (3)	C15—H15A	0.9300
C7—H7	0.9800	C15—H15B	0.9300
C8—C9	1.528 (3)		

O1—S1—O2	119.70 (12)	H8A—C8—H8B	108.1
O1—S1—N1	106.79 (11)	C10—C9—C8	111.75 (18)
O2—S1—N1	107.95 (10)	C10—C9—H9A	109.3
O1—S1—C1	107.60 (10)	C8—C9—H9A	109.3
O2—S1—C1	106.76 (12)	C10—C9—H9B	109.3
N1—S1—C1	107.52 (10)	C8—C9—H9B	109.3
C13—N1—C7	119.21 (17)	H9A—C9—H9B	107.9
C13—N1—S1	119.58 (14)	C11—C10—C9	111.2 (2)
C7—N1—S1	119.19 (14)	C11—C10—H10A	109.4
C6—C1—C2	120.3 (2)	C9—C10—H10A	109.4
C6—C1—S1	119.87 (17)	C11—C10—H10B	109.4
C2—C1—S1	119.82 (19)	C9—C10—H10B	109.4
C3—C2—C1	119.4 (3)	H10A—C10—H10B	108.0
C3—C2—H2	120.3	C10—C11—C12	110.8 (2)
C1—C2—H2	120.3	C10—C11—H11A	109.5
C4—C3—C2	120.7 (3)	C12—C11—H11A	109.5
C4—C3—H3	119.7	C10—C11—H11B	109.5
C2—C3—H3	119.7	C12—C11—H11B	109.5
C3—C4—C5	120.5 (3)	H11A—C11—H11B	108.1
C3—C4—H4	119.8	C7—C12—C11	110.82 (19)
C5—C4—H4	119.8	C7—C12—H12A	109.5
C4—C5—C6	120.0 (3)	C11—C12—H12A	109.5
C4—C5—H5	120.0	C7—C12—H12B	109.5
C6—C5—H5	120.0	C11—C12—H12B	109.5
C5—C6—C1	119.2 (2)	H12A—C12—H12B	108.1
C5—C6—H6	120.4	N1—C13—C14	111.3 (2)
C1—C6—H6	120.4	N1—C13—H13A	109.4
N1—C7—C8	111.04 (17)	C14—C13—H13A	109.4
N1—C7—C12	113.81 (17)	N1—C13—H13B	109.4
C8—C7—C12	110.80 (18)	C14—C13—H13B	109.4
N1—C7—H7	106.9	H13A—C13—H13B	108.0
C8—C7—H7	106.9	C15—C14—C13	127.5 (4)
C12—C7—H7	106.9	C15—C14—H14	116.2
C7—C8—C9	110.76 (19)	C13—C14—H14	116.2
C7—C8—H8A	109.5	C14—C15—H15A	120.0
C9—C8—H8A	109.5	C14—C15—H15B	120.0
C7—C8—H8B	109.5	H15A—C15—H15B	120.0
C9—C8—H8B	109.5		
O1—S1—N1—C13	-22.4 (2)	C2—C1—C6—C5	0.3 (4)
O2—S1—N1—C13	-152.36 (18)	S1—C1—C6—C5	178.25 (19)
C1—S1—N1—C13	92.80 (18)	C13—N1—C7—C8	64.3 (2)
O1—S1—N1—C7	173.87 (15)	S1—N1—C7—C8	-131.93 (17)
O2—S1—N1—C7	43.96 (19)	C13—N1—C7—C12	-61.5 (3)
C1—S1—N1—C7	-70.88 (17)	S1—N1—C7—C12	102.2 (2)
O1—S1—C1—C6	32.0 (2)	N1—C7—C8—C9	176.87 (18)
O2—S1—C1—C6	161.62 (18)	C12—C7—C8—C9	-55.6 (2)
N1—S1—C1—C6	-82.75 (19)	C7—C8—C9—C10	55.1 (3)
O1—S1—C1—C2	-150.1 (2)	C8—C9—C10—C11	-55.4 (3)

supplementary materials

O2—S1—C1—C2	−20.4 (2)	C9—C10—C11—C12	56.1 (3)
N1—S1—C1—C2	95.2 (2)	N1—C7—C12—C11	−177.19 (19)
C6—C1—C2—C3	−0.2 (4)	C8—C7—C12—C11	56.8 (3)
S1—C1—C2—C3	−178.1 (2)	C10—C11—C12—C7	−56.9 (3)
C1—C2—C3—C4	−0.6 (5)	C7—N1—C13—C14	−104.9 (2)
C2—C3—C4—C5	1.3 (5)	S1—N1—C13—C14	91.5 (2)
C3—C4—C5—C6	−1.1 (5)	N1—C13—C14—C15	134.8 (4)
C4—C5—C6—C1	0.3 (4)		

Fig. 1

